

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



Contact us

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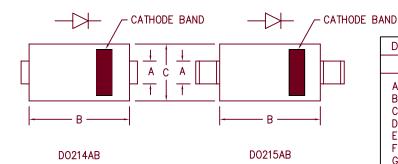
Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China



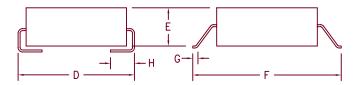




8 Amp Schottky Rectifier HSM825 — HSM845



Dim. Inches			Millimeter		
	Minimum	Maximum	Minimum	Maximum	Notes
Α	.117	.123	2.97	3.12	
В	.260	.280	6.60	7.11	
С	.220	.245	5.59	6.22	
D	.307	.322	7.80	8.18	
E	.075	.095	1.91	2.41	
F	.380	.400	9.65	10.16	
G	.025	.040	.640	1.02	
Н	.030	.060	.760	1.52	



Microsemi Catalog Number	Industry Part Number		Repetitive Peak Reverse Voltage
HSM825*	SK82L	25V	25V
HSM830*	SL83L	30V	30V
HSM835*	SK835L	35V	35V
HSM840*	SK84L	40V	40V
HSM845*	SK845L	45V	45V

- Schottky Barrier Rectifier
- Guard Ring Protection
- 175 C Junction Temperature
- High Current Capability
- VRRM 25 to 45 Volts
- Surface mount package

Electrical Characteristics

Average forward current
Maximum surge current
Max peak forward voltage
Max peak forward voltage
Max peak reverse current
Typical junction capacitance

I F(AV) 8.0 Amps I F(AV) 350 Amps V FM .47 Volts V FM .62 Volts I RM 250 µA CJ 660pF Square wave 8.3ms, half sine, TJ = 175°C IFM = 8.0A:TJ = 150°C * IFM = 8.0A;TJ = 25°C * VRRM,TJ = 25°C VR = 5.0V,TJ = 25°C

* Pulse test: Pulse width 300 jusec, Duty cycle 2%

Thermal and Mechanical Characteristics

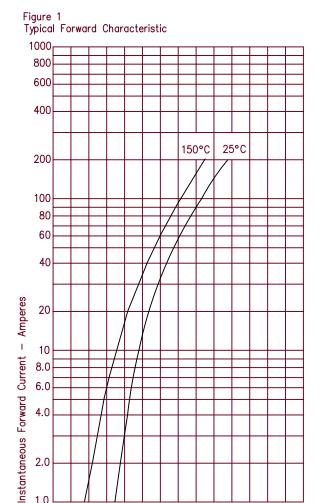
Storage temperature range Operating junction temp range Maximum thermal resistance Weight TSTG TJ ROJL -55°C to 175°C -55°C to 175°C 20°C/W Junction to lead .008 ounces (.22 grams) typical



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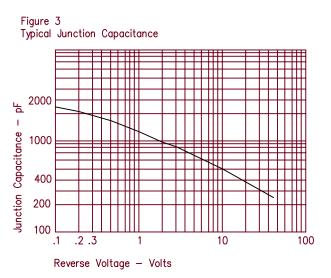
HSM825 - HSM845

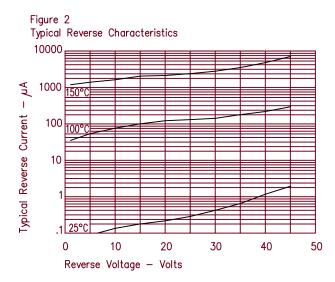


8.0 6.0 4.0

2.0

1.0





Instantaneous Forward Voltage — Volts

.9

1.1

1.3

1.5